# HAMAMATSU

# METAL PACKAGE PHOTOMULTIPLIER TUBE R7400U SERIES

## Compact size (16 mm diameter, 12 mm seated length), Fast Time response (rise time 0.78 ns)

The R7400U series is a subminiature photomultiplier tube with a 16 mm diameter and 12 mm seated length. A precision engineered 8-stage electron multiplier (composed of metal channel dynodes) is incorporated in the TO-8 package to produce a noise free gain of 700,000 times (R7400U). The R7400U series also features excellent response time with a rise time of 0.78 ns. Various types of the R7400U series are available with different spectral response and gain ranges, including those selected specifically for photon counting applications. Hamamatsu also provides a hemispherical lens input option to the series (R7401 and R7402), effectively doubling the active area.



Left: R7400U Right: R7401/R7402

#### FEATURES

- World's smallest photomultiplier tubes assembled in a TO-8 metal package (1/7th of the Hamamatsu R647). The necessary components are built into a TO-8 package while retaining full photomultiplier tube performance to create a new generation of photosensors.
- Photon counting type: R7400P.
  The R7400P is specially selected on account of low noise and high gain for use in photon counting applications.
- Hemispherical lens window types: R7401 (bialkali), R7402 (multialkali). The hemispherical lens window doubles the effective input area to 12 mm in diameter.

#### SERIES

	Solar Blind	UV to Visible Range	UV to Near IR Range	Insulation Cover
Standard	R7400U-09	R7400U/R7400U-03/R7400U-06	R7400U-01/R7400U-02/R7400U-04/R7400U-20	Yes
For Photon Counting		R7400P		Yes
With Lens		R7401 (Visible Range)	R7402 (Visible to Near IR Range)	Yes

#### GENERAL

	Para	meter	Description/Value	Unit
Minimum E	ffective Area		8	mmφ
Dynada	Structure		Metal Channel	
Dynoue	Number of	Stage	8	
Woight	R7400U S	eries/R7400P	Approx. 5.3	
weight	R7401/R74	402/R7401P	Approx. 6.3	g
Ambient Temperature		R7400U Series/R7400P	-80 to +50	•
		R7401/R7402/R7401P	-30 to +50	

### **VOLTAGE DISTRIBUTION RATIO**

Electrodes	ĸ	(	Dy1	D	/2	Dy3	D	y4	D	y5	Dy	/6	D	y7	Dy	/8	Ρ	)
Ratio		1	-	1	1		1	1		1		1		-	1	0.5	;	

Supply Voltage: 800 V K: Cathode Dy: Dynode P: Anode

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## CHARACTERISTICS (at 25 °C)

		Spectral F	Response			<u> </u>	Maximun	n Ratings	Cathode Sensitivity					
Type No.	Remarks	Range	Peak Wave-	Photo- cathode	Window	Out- line	Anode to Cathode	Average Anode	Lumi	nous	Blue(5-58)	Red/White Ratio	Radiant	
		(nm)	length (nm)	Material	Material	No.	Voltage (V dc)	Current (mA)	Min. (μA/lm)	Typ. (μA/lm)	Typ. (μA/lm-b)	Тур. ×10⁻³	Typ. (mA/W)	
R7400U-09	Solar Blind	160 to 320	240	Cs-Te	Synthetic silica	2		0.01	_	_	_	_	<sub>22</sub> (a)	
R7400U	Visible	300 to 650			Borosilicate glass									
R7400U-03		185 to 650	420	Bialkali	UV glass	U			40	70	8	_	62	
R7400U-06		160 to 650			Synthetic silica	2								
R7400U-01	Visible	300 to 850	400				1000(d)		80	150		200	60	
R7400U-02		300 to 880	500	Marchiller II. a. II.	Borosilicate glass 1		1000(-)	0.1(e)	200	250		250	58	
R7400U-20	UV to Near IR	300 to 900	630	Multialkali				350	500	_	450	78 (at 630 nm)		
R7400U-04		185 to 850	400		UV glass				80	150		200	60	
R7401	With Long	300 to 650	420	Bialkali	Borosilicate glass	3			40	70	8	_	62	
R7402	with Lefts	300 to 850	400	Multialkali	Dorosilicate glass				80	150	_	200	60	

(a): Measured at 254 nm.

(b): Measured after a 30-minute storage in darkness.

(c): Measured at a gain of 106





WAVELENGTH (nm)









Figure 4: Typical Gain Characteristics



HAMAMAT5U
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Anode to				Anode C	Character	istics			
Cathode Supply Voltage (V dc)	And	Anode Sensitivity			Anode	Dark <sup>(b)</sup>	Time Re	Type No.	
	Lum Min. (A/Im)	nous Typ. (A/lm)	Radiant Typ. (A/W)	Typ.	Typ. (nA)	Max. (nA)	RiseTime Typ. (ns)	Electron Transit Time Typ. (ns)	,
	_	-	1100(a)	$5  imes 10^4$	0.025	0.5			R7400U-09
			50 4.3 × 10 <sup>4</sup>		0.2		- 0.78	5.4	R7400U
	10 50	50		7 × 10 <sup>5</sup>		2			R7400U-03
									R7400U-06
800	15	75	$3.0 imes10^4$		0.4	4			R7400U-01
800	25	125	$2.9 imes10^4$	<b>5</b> 105	0	20			R7400U-02
	35	250	$3.9 imes10^4$	5 × 10°	2	20			R7400U-20
	15	75	$3.0 imes10^4$		0.4	4			R7400U-04
	10	50	$4.3 imes10^4$	$7  imes 10^5$	0.2	2	]		R7401
	15	75	$3.0  imes 10^4$	5×10 <sup>5</sup>	0.4	4			R7402

For Photon Counting (P Type)									
Type No.	Ga	ain	Dark Count (c) (s <sup>-1</sup> )						
	Min.	Тур.	Тур.	Max.					
R7400P	7.5 \(105)	1 \(106)	00	400					
R7401P	7.5×10-	1×10*	80	400					

(e): The output current averaged over 30 seconds should not exceed 0.1 mA.







Figure 6: Anode Dark Current (v.s. Supply Voltage)



Figure 8: Transmittance of Lens



#### Figure 9: Lens Effect



MEASUREMENT CONDITIONS WAVELENGTH : 400 nm SUPPLY VOLTAGE : -800 V A 1 mm diameter spot light (parallel light) is scanned at the center of the photocathode in X and Y directions.

TPMHC0153EA

#### Figure 10: Lens Effect



Parallel light : Parallel Light: from a 40 mm diameter parallel light source insuring uniform intensity over the entire active area of the photomultiplier tube. Diffused light: Diffused light: from a 40 mm diameter parallel light source and a diffuser placed 10cm from the detector. The entire active area of the PMT is exposed.

#### Figure 11: Dimensional Outline and Basing Diagram (Unit: mm)



2R7400U-06,-09



3R7401, R7402, R7401P



## ACCESSORIES OPTION

#### Socket E678-12M



#### • D Type Socket Assemblies E5770/E5780

The E5770 and E5780 are compact socket assemblies incorporating a voltage divider circuit comprised of resistors and capacitors. These socket assemblies are designed to provide the output signal directly from the anode of the metal package photomultiplier tube.

Type No.	Grounded	Divider Resistance	Maximum Linear Output of Photomultiplier Tube	Output	Signal
	Liectiode	(Total)	(DC Mode)	Cathode Grounded	Anode Grounded
E5770	Anode/Cathode	0.0140		Pulse	DC/Pulse
E5780	Anode	2.8 MΩ	13 μΑ		DC/Pulse

\* When the E5770 is used with the anode at a positive high voltage, the negative high voltage (-HV) terminal should be grounded and a positive high voltage applied to the ground terminal. In this arrangement, a high voltage differential is generated between the output and an external amplifier, so use a decoupling capacitor that can withstand a high voltage.

\*\* In the E5780, the shield of the signal output cable is connected to the grounded cable, so the E5780 can be used only for negative high voltage operation. Consult our sales office when the E5780 is needed for positive high voltage operation.



#### • DA Type Socket Assembly C5781

The C5781 is a subminiature socket assembly that incorporates a voltage divider circuit and a low-noise amplifier.

#### **SPECIFICATION of Built-in Amplifier**

Parameter	Value	Unit
Input Voltage for Amplifier	±15	V
Current to Voltage Conversion Factor	1	V/µA
Maximum Output Voltage (with no load resistor)	10	V
Bandwidth (-3 db)	DC to 20	kHz Typ.



#### Compact High Voltage Power Supply Units C4900 Series

The C4900 series is an on-board type high voltage power supply unit, with a design that aims at providing both "compactness and high performance".

The newly developed circuit achieves high performance and low power consumption. The C4900 series in addition provides enhanced protective functions yet is offered at lower costs.



#### SPECIFICATION

Parameter		C4900	C4900-01	C4900-50	C4900-51	
Input Voltage		+15 V dc	+12 V dc	+15 V dc	+12 V dc	
Input Current	€	14 mA	15 mA	14 mA	15 mA	
*A	2	90 mA	95 mA	90 mA	95 mA	
Variable Output Ra	nge	0 V to -	1250 V	0 V to +	-1250 V	
Maximum Output Cu	ırrent	0.6 mA	0.5 mA	0.6 mA	0.5 mA	
Ripple Noise		0.007 % р-р Тур.				
Line Regulation	*B	±0.01 % p-p Typ.				
Load Regulation	ı *C		±0.01 %	р-р Тур.		

 $\textcircled{1}\$  with no load

2 with full load

\*A: at maximum output voltage

\*B: against ±1 V Change.

\*C: against 0 to 100 % Load Change.

#### WARNING: HIGH VOLTAGE



The metal package photomultiplier tubes are operated by applying a high voltage. Use extreme caution to avoid electrical shock and damage to the peripheral equipment and be sure to provide adequate safety measures as needed. As safety measures, an insulation cover is fitted to the metal package which is electrically connected to the photocathode. When operated with the cathode at a high voltage (anode ground scheme), the metal package will be at this same high voltage level. Removing the insulation cover is extremely dangerous, so never attempt to remove it from the package.

## **RELATED PRODUCTS**

#### PHOTOSENSOR MODULES H6779/H6780/H5784 SERIES

The H6779/H6780 series are new light sensor modules including the compact photomultiplier tube, (METAL PACKAGE PMT) and operating power supply. It features low voltage operation (+15 V) and low power consumption (Approx. 450 mW for H6779/H6780). Compared with current light sensors, it has several advantages like high sensitivity, wide dynamic range and fast time response. These are featured by the PMT and the Cockcroft-Walton high voltage power supply. The H5773/H6779 series are on-board types which facilitates mounting directly on a printed circuit board and the H5783/H6780 series have a cable output. H5784 series are cable out type with an amplifier of DC to 20 kHz bandwidth. These versions accept direct light input or an optical fiber with the optional fiber connector of E5776.

# Left: H6780 Center: H6779 Right: H6779 with E5776 Front: METAL PACKAGE PMT



- Low Power Consumption
- Low Voltage Drive
- Easy to Use
- High Sensitivity
- Wide Dynamic Range
- Fast Time Response

Please refer the individual detail data sheet of H6779/H6780/H5784 series

H6779 Series

HIGH VOLTAGE

POWER SUPPLY

TPMHC0093EB

#### PATENT: USA 1 (PAT. No. 5410211) PATENT PENDING: JAPAN 12, USA 8, EUROPE 9



HOMEPAGE URL http://www.hamamatsu.com

METAL PACKAGE PMT

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